

TOSHIBA CMOS LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

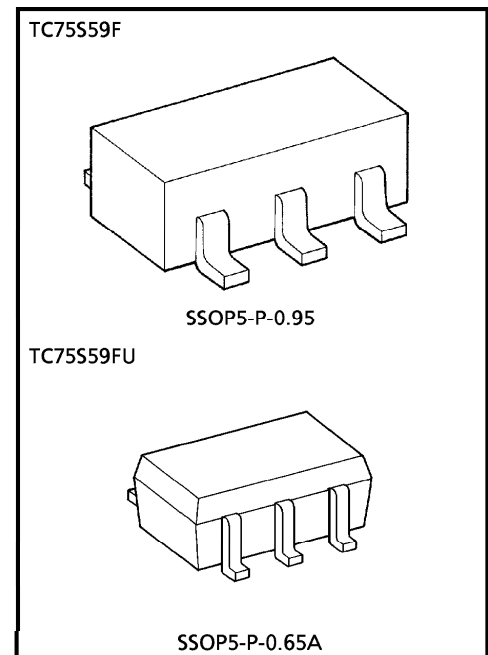
TC75S59F, TC75S59FU

SINGLE COMPARATOR

TC75S59F, TC75S59FU are CMOS type general-purpose single comparator capable of single power supply operation and using lower supply currents than the conventional bipolar comparators. Its open drain output forms wired OR with other open drain outputs.

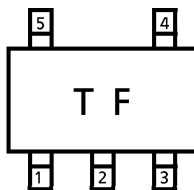
FEATURES

- Low supply current : $I_{DD} = 100\mu A$ (Typ.)
- Single power supply operation
- Wide common mode input voltage range : $V_{SS} \sim V_{DD} - 0.9V$
- Open drain output circuit
- Low input bias current
- Small package

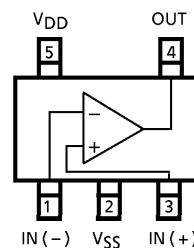


Weight
 SSOP5-P-0.95 : 0.014g (Typ.)
 SSOP5-P-0.65A : 0.006g (Typ.)

MARKING (TOP VIEW)



PIN CONNECTION (TOP VIEW)



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MAXIMUM RATINGS (Ta = 25°C)

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|----------------------------|-----------------------------------|----------------------------------|------|
| Supply Voltage | V _{DD} , V _{SS} | ± 3.5 or 7 | V |
| Differential Input Voltage | DV _{IN} | ± 7 | V |
| Input Voltage | V _{IN} | V _{SS} ~V _{DD} | V |
| Output Current | I _O | ± 35 | mA |
| Power Dissipation | P _D | 200 | mW |
| Operating Temperature | T _{opr} | - 40~85 | °C |
| Storage Temperature | T _{stg} | - 55~125 | °C |

(Note) Since this product sometimes brings about latchup, which is peculiar to CMOS devices, note the following points :

- Don't raise the voltage level of I/O pins beyond V_{DD}, nor lower it below V_{SS}. Consider the timing for power supply, too.
- Don't let any abnormal noise enter the device.

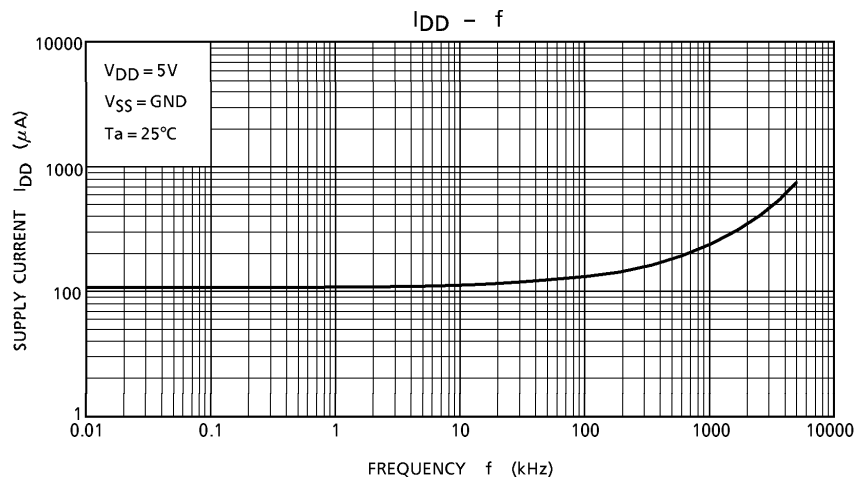
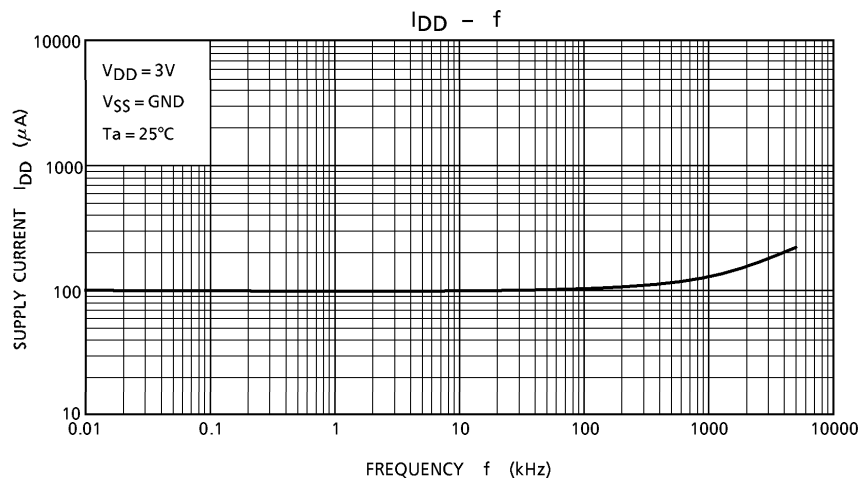
ELECTRICAL CHARACTERISTICS ($V_{DD} = 5V$, $V_{SS} = GND$, $T_a = 25^\circ C$)

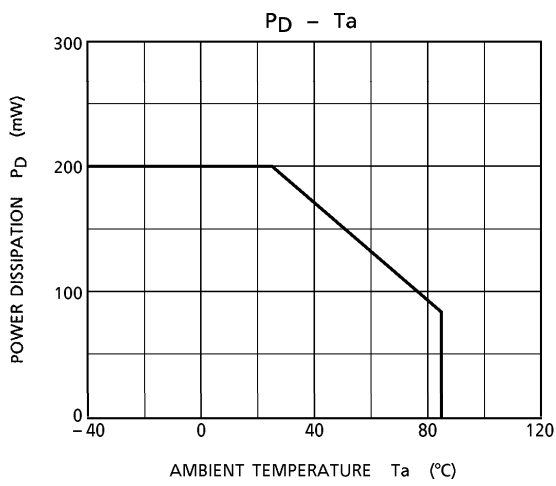
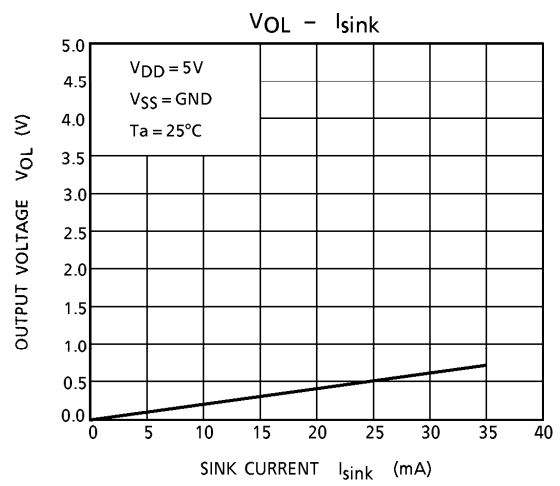
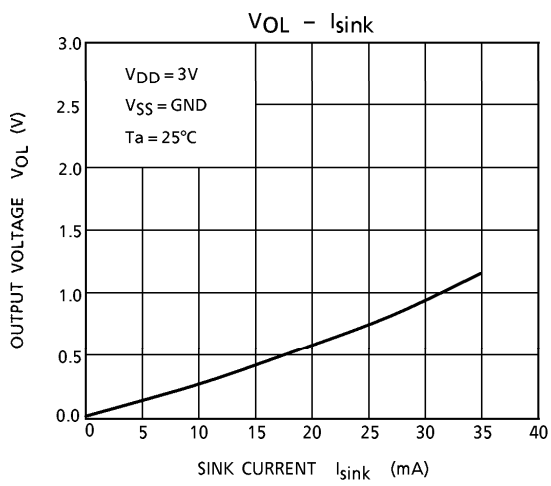
| CHARACTERISTIC | SYMBOL | TEST CIR-CUIT | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|-----------------------------------|-----------------|---------------|--------------------|------|---------|---------|---------|
| Input Offset Voltage | V_{IO} | — | — | — | ± 1 | ± 7 | mV |
| Input Offset Current | I_{IO} | — | — | — | 1 | — | pA |
| Input Bias Current | I_I | — | — | — | 1 | — | pA |
| Common Mode Input Voltage | CMV_{IN} | — | — | 0 | — | 4.1 | V |
| Supply Current | I_{DD} (Note) | — | — | — | 110 | 220 | μA |
| Voltage Gain | G_V | — | — | — | 94 | — | dB |
| Sink Current | I_{sink} | — | $V_{OL} = 0.5V$ | 13 | 25 | — | mA |
| Output Leak Current | I_{LEAK} | — | $V_O = 5V$ | — | 5 | — | nA |
| Output Voltage | V_{OL} | — | $I_{sink} = 5.0mA$ | — | 0.1 | 0.3 | V |
| Operating Supply Voltage | V_{DD} | — | — | 1.8 | — | 7.0 | V |
| Propagation Delay Time (Turn ON) | t_{PLH} (1) | — | Over drive = 100mV | — | 200 | — | ns |
| | t_{PLH} (2) | — | TTL step input | — | 140 | — | |
| Propagation Delay Time (Turn OFF) | t_{PHL} (1) | — | Over drive = 100mV | — | 80 | — | ns |
| | t_{PHL} (2) | — | TTL step input | — | 60 | — | |
| Response Time | t_{TLH} | — | Over drive = 100mV | — | 160 | — | ns |
| | t_{THL} | — | Over drive = 100mV | — | 3 | — | |

ELECTRICAL CHARACTERISTICS ($V_{DD} = 3V$, $V_{SS} = GND$, $T_a = 25^\circ C$)

| CHARACTERISTIC | SYMBOL | TEST CIR-CUIT | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|-----------------------------------|-----------------|---------------|--------------------|------|---------|---------|---------|
| Input Offset Voltage | V_{IO} | — | — | — | ± 1 | ± 7 | mV |
| Input Offset Current | I_{IO} | — | — | — | 1 | — | pA |
| Input Bias Current | I_I | — | — | — | 1 | — | pA |
| Common Mode Input Voltage | CMV_{IN} | — | — | 0 | — | 2.1 | V |
| Supply Current | I_{DD} (Note) | — | — | — | 100 | 200 | μA |
| Sink Current | I_{sink} | — | $V_{OL} = 0.5V$ | 6 | 18 | — | mA |
| Output Leak Current | I_{LEAK} | — | $V_O = 3V$ | — | 5 | — | nA |
| Output Voltage | V_{OL} | — | $I_{sink} = 5.0mA$ | — | 0.15 | 0.35 | V |
| Propagation Delay Time (Turn ON) | t_{PLH} | — | Over drive = 100mV | — | 160 | — | ns |
| Propagation Delay Time (Turn OFF) | t_{PHL} | — | Over drive = 100mV | — | 70 | — | ns |
| Response Time | t_{TLH} | — | Over drive = 100mV | — | 170 | — | ns |
| | t_{THL} | — | Over drive = 100mV | — | 3 | — | |

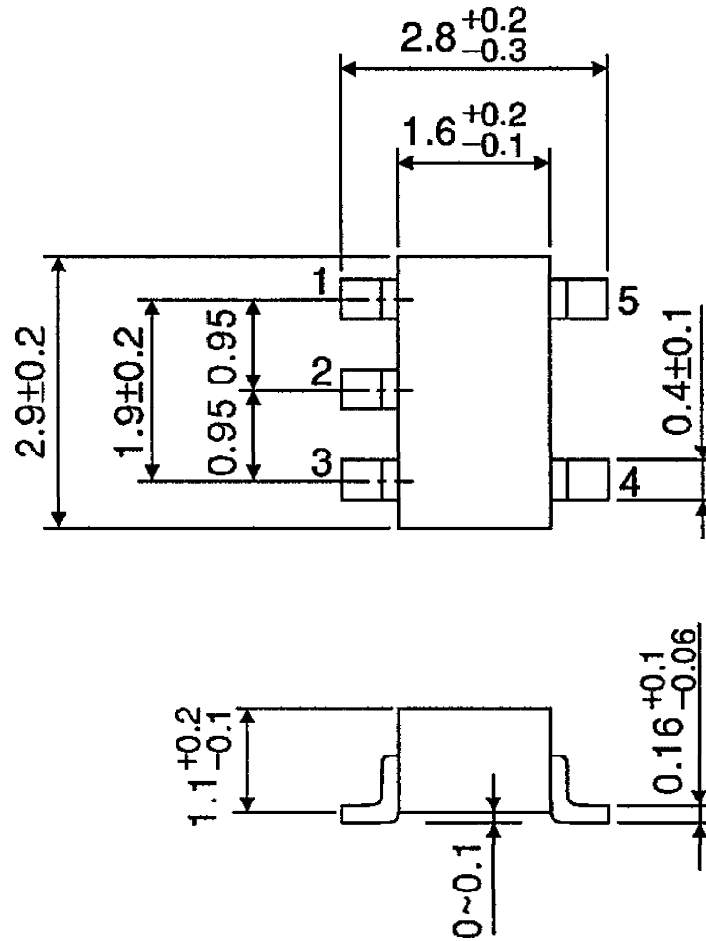
(Note) Since this product causes an increase in current consumption with a rise in operational frequency, make sure that power consumption does not exceed the allowable dissipation.





OUTLINE DRAWING
SSOP5-P-0.95

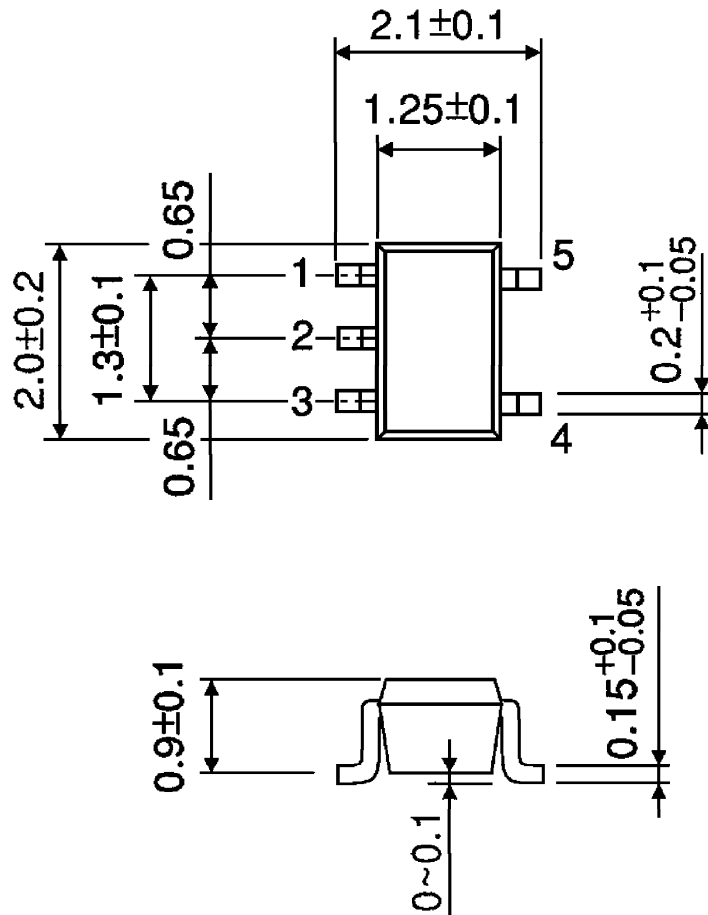
Unit : mm



Weight : 0.014g (Typ.)

OUTLINE DRAWING
SSOP5-P-0.65A

Unit : mm



Weight : 0.006g (Typ.)